Memory Microcircuit - Page 1 of 1



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Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

Pacer dawn

Features Provided:

Electrostatic sensitive and hermetically sealed and monolithic and radiation hardened

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Criticality Code Justification:

Cbbl

Case Outline Source And Designator:

D-7 mil-m-38510

Product Name:

Microcircuit, digital, cmos, 16kx4 bit static ram, monolithic silicon

Voltage Rating And Type Per Characteristic:

-0.3 volts total supply and 7.0 volts total supply

Memory Device Type:

Ram

Terminal Type And Quantity:

22 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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